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[Vishay Semiconductor/Diodes Division](#)
[VS-UFB170FA60](#)

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VS-UFB170FA60


Vishay Semiconductors

Insulated Ultrafast Rectifier Module, 170 A



SOT-227

FEATURES

- Two fully independent diodes
- Fully insulated package
- Ultrafast, soft reverse recovery, with high operation junction temperature (T_J max. = 175 °C)
- Very low forward voltage drop
- Optimized for power conversion: welding and industrial SMPS applications
- Easy to use and parallel
- Industry standard outline
- UL approved file E78996 
- Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



RoHS
COMPLIANT

PRODUCT SUMMARY	
V_R	600 V
$I_{F(AV)}$ per module at $T_C = 76$ °C	170 A
t_{rr}	60 ns
Type	Modules - Diode FRED Pt®
Package	SOT-227

DESCRIPTION / APPLICATIONS

The VS-UFB170FA60 insulated modules integrate two state of the art ultrafast recovery rectifiers in the compact, industry standard SOT-227 package. The diodes structure, and its life time control, provide an ultrasoft recovery current shape, together with the best overall performance, ruggedness and reliability characteristics.

These devices are thus intended for high frequency applications in which the switching energy is designed not to be predominant portion of the total energy, such as in the output rectification stage of welding machines, SMPS, DC/DC converters. Their extremely optimized stored charge and low recovery current reduce both over dissipation in the switching elements (and snubbers) and EMI/RFI.

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS
Cathode to anode voltage	V_R		600	V
Continuous forward current per diode	I_F	$T_C = 90$ °C	94	A
Single pulse forward current per diode	I_{FSM}	$T_C = 25$ °C	850	
Maximum power dissipation per module	P_D	$T_C = 90$ °C	233	W
RMS isolation voltage	V_{ISOL}	Any terminal to case, $t = 1$ minute	2500	V
Operating junction and storage temperatures	T_J, T_{Stg}		-55 to +175	°C



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ELECTRICAL SPECIFICATIONS PER DIODE ($T_J = 25\text{ }^\circ\text{C}$ unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Cathode to anode breakdown voltage	V_{BR}	$I_R = 100\text{ }\mu\text{A}$	600	-	-	
Forward voltage, per leg	V_{FM}	$I_F = 50\text{ A}$	-	1.02	1.19	V
		$I_F = 50\text{ A}, T_J = 175\text{ }^\circ\text{C}$	-	0.87	-	
		$I_F = 100\text{ A}$	-	1.17	1.43	
		$I_F = 100\text{ A}, T_J = 175\text{ }^\circ\text{C}$	-	1.03	-	
Reverse leakage current, per leg	I_{RM}	$V_R = V_R\text{ rated}$	-	0.5	50	μA
		$T_J = 175\text{ }^\circ\text{C}, V_R = V_R\text{ rated}$	-	0.1	2	mA
Junction capacitance, per leg	C_T	$V_R = 600\text{ V}$	-	43	-	pF

DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25\text{ }^\circ\text{C}$ unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Reverse recovery time, per leg	t_{rr}	$T_J = 25\text{ }^\circ\text{C}, I_F = 1\text{ A } dI_F/dt = 200\text{ A}/\mu\text{s } V_R = 30\text{ V}$	-	60	-	ns
		$T_J = 25\text{ }^\circ\text{C}$	-	170	-	
		$T_J = 125\text{ }^\circ\text{C}$	-	270	-	
Peak recovery current, per leg	I_{RRM}	$T_J = 25\text{ }^\circ\text{C}$	-	40	-	A
		$T_J = 125\text{ }^\circ\text{C}$	-	54	-	
Reverse recovery charge, per leg	Q_{rr}	$T_J = 25\text{ }^\circ\text{C}$	-	3.4	-	μC
		$T_J = 125\text{ }^\circ\text{C}$	-	6.8	-	
Reverse recovery time, per leg	t_{rr}	$T_J = 25\text{ }^\circ\text{C}$	-	220	-	ns
		$T_J = 125\text{ }^\circ\text{C}$	-	300	-	
Peak recovery current, per leg	I_{RRM}	$T_J = 25\text{ }^\circ\text{C}$	-	47	-	A
		$T_J = 125\text{ }^\circ\text{C}$	-	61	-	
Reverse recovery charge, per leg	Q_{rr}	$T_J = 25\text{ }^\circ\text{C}$	-	5.2	-	μC
		$T_J = 125\text{ }^\circ\text{C}$	-	9.1	-	

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Junction to case, single leg conducting	R_{thJC}		-	-	0.73	$^\circ\text{C}/\text{W}$
Junction to case, both leg conducting			-	-	0.365	
Case to heatsink	R_{thCS}	Flat, greased surface	-	0.10	-	
Weight			-	30	-	g
Mounting torque		Torque to terminal	-	-	1.1 (9.7)	Nm (lbf.in)
		Torque to heatsink	-	-	1.3 (11.5)	Nm (lbf.in)
Case style			SOT-227			



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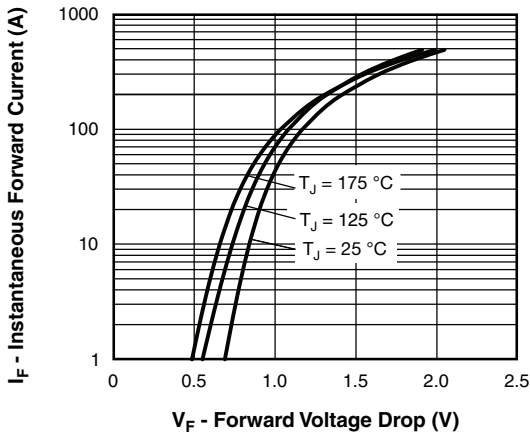


Fig. 1 - Typical Forward Voltage Drop Characteristics (Per Leg)

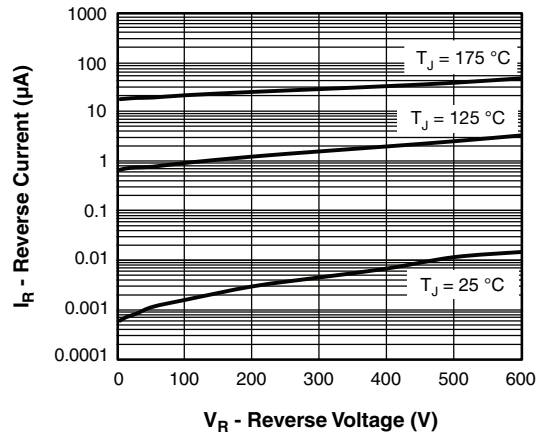


Fig. 2 - Typical Reverse Current vs. Reverse Voltage (Per Leg)

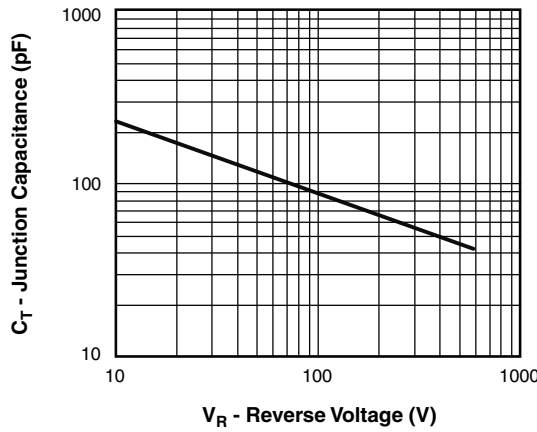


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

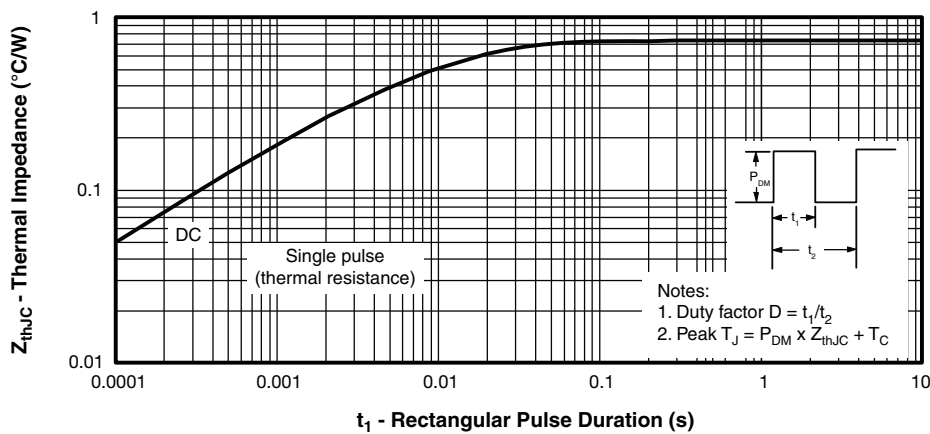


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)



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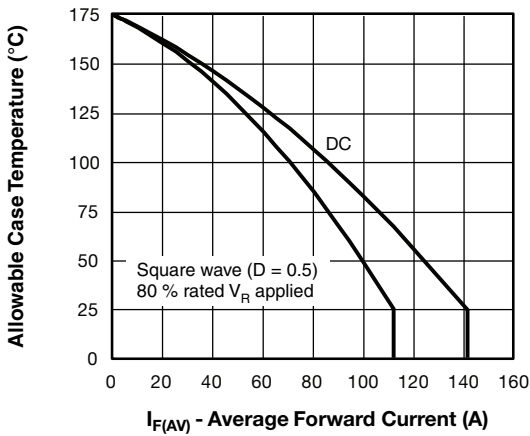


Fig. 5 - Allowable Case Temperature vs. Average Forward Current (Per Leg)

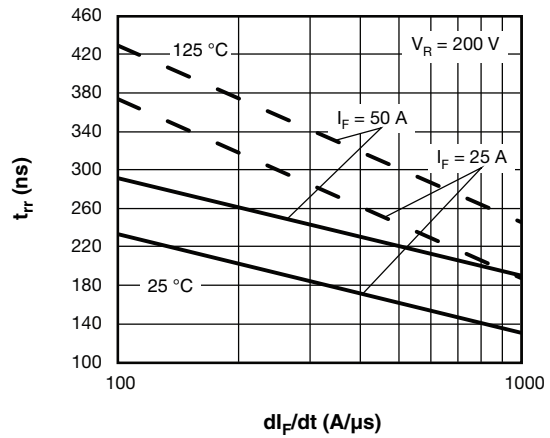


Fig. 7 - Typical Reverse Recovery Time vs. di_F/dt (Per Leg)

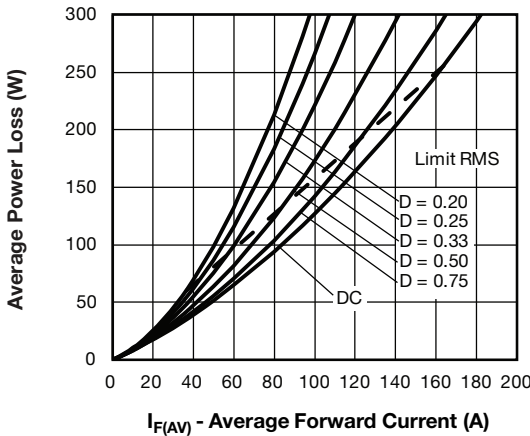


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

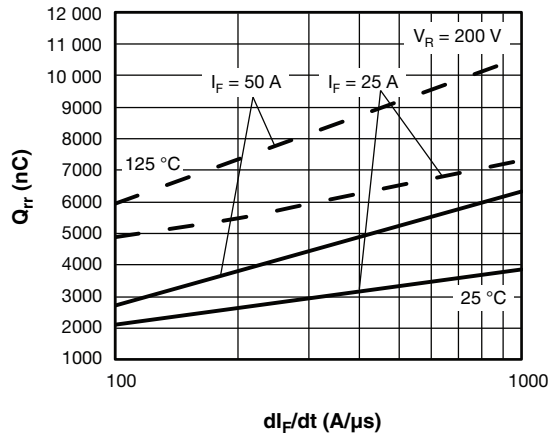


Fig. 8 - Typical Stored Charge vs. di_F/dt (Per Leg)

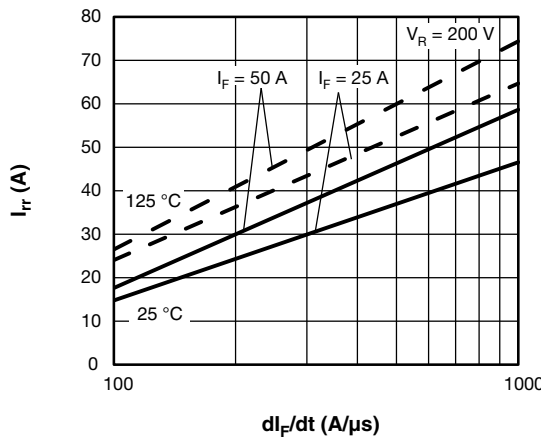


Fig. 9 - Typical Recovery Current vs. di_F/dt (Per Leg)



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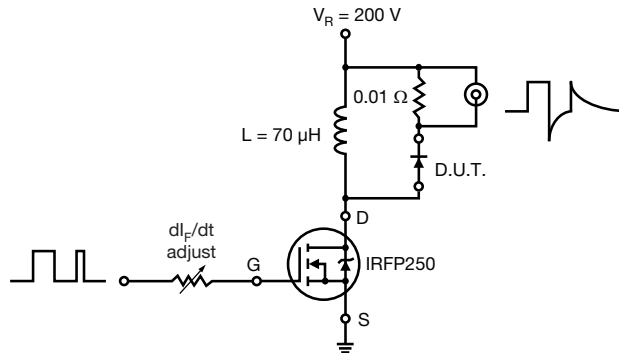
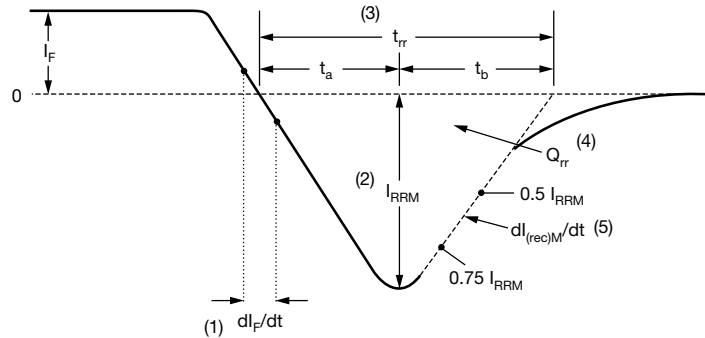


Fig. 10 - Reverse Recovery Parameter Test Circuit



- (1) di_F/dt - rate of change of current through zero crossing
- (2) I_{RRM} - peak reverse recovery current
- (3) t_{rr} - reverse recovery time measured from zero crossing point of negative going I_F to point where a line passing through $0.75 I_{RRM}$ and $0.50 I_{RRM}$ extrapolated to zero current.
- (4) Q_{rr} - area under curve defined by t_{rr} and I_{RRM}
- (5) $di_{(rec)M}/dt$ - peak rate of change of current during t_b portion of t_{rr}

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

Fig. 11 - Reverse Recovery Waveform and Definitions



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ORDERING INFORMATION TABLE

Device code	VS-	UF	B	170	F	A	60
	①	②	③	④	⑤	⑥	⑦

- 1** - Vishay Semiconductors product
- 2** - Ultrafast rectifier
- 3** - Ultrafast FRED Pt[®] diffused
- 4** - Current rating (170 = 170 A)
- 5** - Circuit configuration (2 separate diodes, parallel pin-out)
- 6** - Package indicator (SOT-227 standard insulated base)
- 7** - Voltage rating (60 = 600 V)

CIRCUIT CONFIGURATION		
CIRCUIT	CIRCUIT CONFIGURATION CODE	CIRCUIT DRAWING
2 separate diodes, parallel pin-out	F	

LINKS TO RELATED DOCUMENTS	
Dimensions	www.vishay.com/doc?95423
Packaging information	www.vishay.com/doc?95425

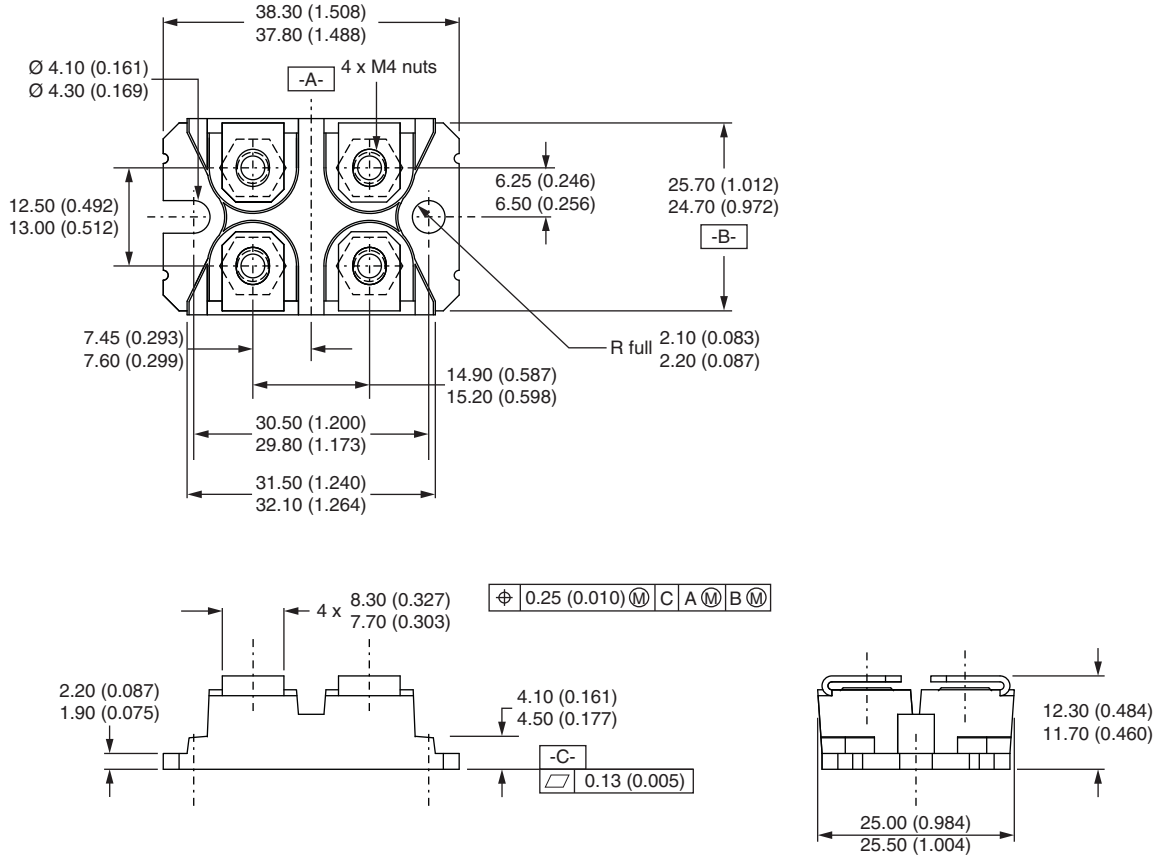


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Outline Dimensions
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SOT-227 Generation II

DIMENSIONS in millimeters (inches)



Note

- Controlling dimension: millimeter



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